

2N3702 through 2N 3706 MPS 3702 through MPS 3706

CASE TO-92B

CASE TO-92A

PNP . NPN SILICON GENERAL PURPOSE AF TRANSISTORS A CALE AND A CALE AND

THE ABOVE TYPES ARE SILICON PLANAR EPITAXIAL TRANSISTORS FOR GENERAL PURPOSE AF MEDIUM POWER APPLICATIONS. THE 2N3702 SERIES ARE SUPPLIED IN CASE TO-92B. THE MPS3702 SERIES ARE SUPPLIED IN CASE TO-92A.

CADE IU-JZA.			·		
		(PNP)	<u>ECB</u>	(NPN)	EBC (NPN)
ABSOLUTE MAXIMUM RATINGS		2N/MPS3702	2N/MPS3703	2N/MPS3704 2N/MPS3705	2N/MPS3706
Collector-Base Voltage	VCBO	40 V	50 v	50 v	40 V
Collector-Emitter Voltage	VCEO	25 V	30V	30 V	20 V
Emitter-Base Voltage	$v_{\rm EBO}$	5 V	5 v	5 v	5 v
Collector Current	IC	0.24	0.2A	0.8A	0.84
Collector Peak Current	ICM	0.6A	0.64	$\mathbf{w}_{\mathbf{k},\mathbf{k}} \in \mathcal{L}$	
Total Power Dissipation (TC ≤ 25 °C)	P_{tot}		1	W	
(T A≤25°C)			360	mW	
Operating Junction & Storage	Tj, Ts	stg	-55 to	150°C	

Temperature

ELECTRICAL CHARACTERISTICS ($T_{A=25^{\circ}C}$ unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CON	ITIONS
Collector-Base Breakdown Voltage	BVCBO	Ť			V	IC=0.1mA	IE=0
Collector-Emitter Breakdown Voltage	LVCEO *	Note	1		v	IC=10mA	IBO
Emitter-Base Breakdown Voltage	BVEBO	↓			v	IE=0.1mA	IC=0
Collector Cutoff Current	ICBO			100	nA	VCB=20V	IE=0
Emitter Cutoff Current	IEBO			100	nA	VEB=3V	IC=0
Collector-Emitter Saturation Voltage 2N/MPS3702,3 2N/MPS3704 2N/MPS3705 2N/MPS3706	VCE(sat)	*	0.1 0.12 0.15 0.15		V V V V	IC=50mA IC=100mA IC=100mA IC=100mA	IB=5mA
Base-Emitter Voltage 2N/MPS3702,3 2N/MPS3704,5,6	V _{BE} *	0.6	0.78 0.83	1 1	V V	Ic=50mA Ic=100mA	VCE=5V VCE=2V
D.C. Current Gain 2N/MPS3702 2N/MPS3703 2N/MPS3704	Нре *	60 30 100		300 150 300		IC=50mA IC=50mA IC=50mA	VCE=5V VCE=5V VCE=2V

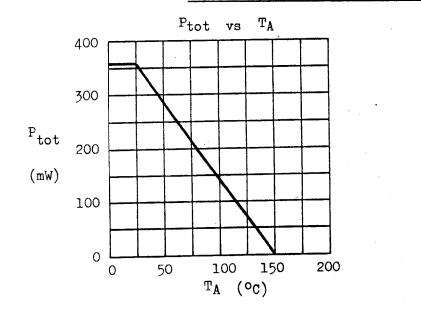
FAX: 3-410321

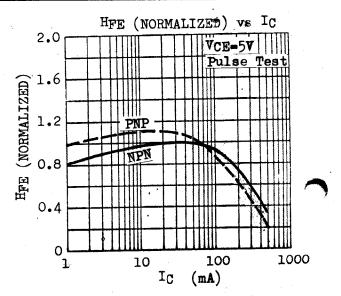
		nued -	nued					
PA	RAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CON	DITIONS
D.C. Current Gain	2N/MPS3705 2N/MPS3706	HFE *	50 30		150 600	-	IC=50mA IC=50mA	VCE=2V VCE=2V
Current Gain-Bandwi	dth Product 2N/MPS3702,3 2N/MPS3704,5,6	f _T	100 100			MHz MHz	IC=50mA IC=50mA	VCE=5V VCE=2V
Collector-Base Capa	citance 2N/MPS3702,3 2N/MPS3704,5,6	Сор		5 4	12 12	pF pF	VCB=10V f=1MHz	IE=0

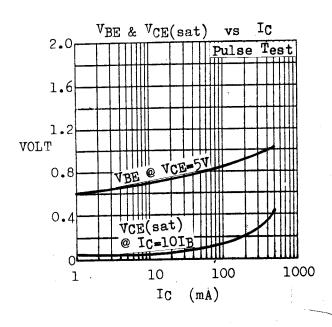
Note 1 : equal to the values of absolute maximum ratings.

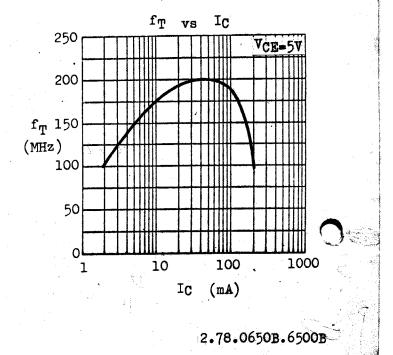
* Pulse Test : Pulse Width=0.3mS, Duty Cycle=1%

TYPICAL CHARACTERISTICS (TA=25°C unless otherwise noted)



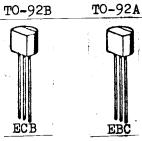


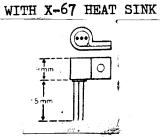




TRANSISTORS EQUIVALENT TO 2N/MPS3702 FAMILY

THE FOLLOWING TRANSISTORS, WHICH ARE CLOSELY EQUIVALENT TO THE 2N/MPS3702 FAMILY, ARE ALSO AVAILABLE.





						CB EBC		\$*
SP	ECIFICATI	ONS AT TA=2			vices, voltage and current			fm @ Ta
TYPE	POLARITY	CASE	LVCEO		ICBO @ VCB		VCE(sat) @ IC/IB	
		(P_{tot})	(V)	(v)	(V) (Au)	(mA) (V)		(MHz)(mA)
			min	min	max	min-max	max	min
2 N 3402			25	5	0.1@25	75-225 @ 2/4.5	0.3 @ 50/3	and the second s
2N3403		TO-92B with X-67	25	5	0.1 @ 25	180-540 @ 2/4.5	0.3 @ 50/3	
2N3404	NPN	Heat Sink	50	5	0.1 @ 50	75-225 @ 2/4.5	0.3 @ 50/3	
2 N 3405		(560mW)	50	- 5	0.1 @ 50	180-540 @ 2/4.5		
2N4425		:	40	5	*0.03 @ 40	180-540 @ 2/4·5	0.3 @ 50/3	a san ing ang ang ang ang ang ang ang ang ang a
2N3414			25	5	0.1 @ 25	75-225 @ 2/4.5	0.3 @ 50/3	
2 N3 415	NPN	то-92в	2-5	5	0.1 @ 25	180-540 @ 2/4,5	0.3 @ 50/3	
2 N3416	1	(360mW)	50	5	0.1 @ 50	75-225 @ 2/4.5	0,3 @ 50/3	
2N3417			50	5	0.1 @ 50	180-540 @ 2/4.5		
2N4424			- 40	5	*0. 03@ 40	180-540 @ 2/4.5	0.3 @ 50/3	
2n5220	NPN	TO-92A (350mW)	15	3	0.1 @ 10	25- @ 10/10 30-600 @ 50/10	0.5 @ 150/15	100 @ 20
2N5221	PNP		15	3	0.1 @ 10	25 - @ 10/10 30-600 @ 50/10	0.5 @ 150/15	100 @ 20
2N5225	NPN		25	4	0.3@15	25- @ 10/10 30-600 @ 50/10	0.8 @ 100/10	50 @ 20
2 N 5226	PNP		25	4	0.3 @:15	25 - @ 10/10 30-600 @ 50/10	0.8 @ 100/10	50 G 20
2N5354	PNP		25	4	* 0 . 1 @ 25	40-120 @ 50/1 20- @ 300/5		
2 N 5355	PNP	TO-92B (3 <u>6</u> 0mW)	25	4	*0.1 @ 25	100-300 @ 50/1 40- @ 300/5	0.25 @ 50/2.5 1.0 @ 300/30	
2N5356	PNP		25	4	* 0 . 1 @ 25	250-500 @ 50/1 75- @ 300/5		
2N5365	PNP		40	4	*0.1 @ 40	40-120 @ 50/1 20- @ 300/5		
2n5366	PNP	TO-92B (360mW)	40	4.	*0.1 @ 40	100-300 @ 50/1 40- @ 300/ 5	0.25 @ 50/2.5 1:0 @ 300/30	
2N5367	PNP		40	4	* 0 .1 @ 4 0	250-500 @ 50/1 75	4	

* ICES

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- - Continued - - -

TYPE	POLARITY	CASE (Ptot)	LVCEO (V)	BVEBO (V)	ICES (µA)	◎ V _{CE} (V)		IC/VCE nA)(V)	VCE(sat) (V)	@ I _C /IB (mA)(mA)	f _T @ IC (MHz)(mA)
			min	min	max		min-max		max		min
2N5418	NPN		25	4	0.1	@ 25	40 - 120 20-	@ 50/1 @ 300/5			
2N5419	NPN	TO-92B (400mW)	25	4	0.1	@ 25	100-300 40-	@ 50/1 @ 300/5	0.25 @ 1.0 @		
2 N 5420	NPN		25	4	.0.1	@ 25	250 - 500 75-	@ 50/1 @ 300/5			
2N5447	PNP										· · ·
2N5448	PNP				m O	0078 +-	nonai ata	ma Mihá	tn olootn	vicol	
2n5449	NPN		These are TO-92F transistors. Their electrical characteristics are exactly identical to 2N3702, 3, 4, 5, 6 respectively.								
2N5450	NPN		21	NJ (UZ,), 4,	9,0	Teshece	τ×ατλ «			
2N5451	NPN										

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